

Power MOSFET

4.0A, 700V N-CHANNEL POWER MOSFET

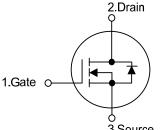
DESCRIPTION

The UTC **4N70K-TA** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche. This high speed switching power MOSFET is usually used in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

FEATURES

- * $R_{DS(ON)}$ < 3.5 Ω @ V_{GS} = 10 V, I_D = 2 A
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

SYMBOL



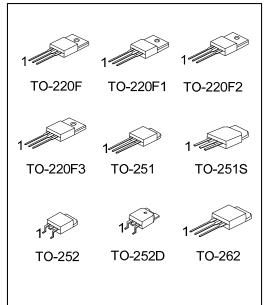
3.Source

ORDERING INFORMATION

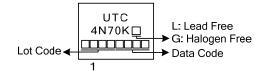
Ordering Number		Dookogo	Pin Assignment			Decking
Lead Free	Halogen Free	Package	1	2	3	Packing
4N70KL-TF3-T	4N70KG-TF3-T	TO-220F	G	D	S	Tube
4N70KL-TF1-T	4N70KG-TF1-T	TO-220F1	G	D	S	Tube
4N70KL-TF2-T	4N70KG-TF2-T	TO-220F2	G	D	S	Tube
4N70KL-TF3T-T	4N70KG-TF3T-T	TO-220F3	G	D	S	Tube
4N70KL-TM3-T	4N70KG-TM3-T	TO-251	G	D	S	Tube
4N70KL-TMS-T	4N70KG-TMS-T	TO-251S	G	D	S	Tube
4N70KL-TN3-R	4N70KG-TN3-R	TO-252	G	D	S	Tape Reel
4N70KL-TND-R	4N70KG-TND-R	TO-252D	G	D	S	Tape Reel
4N70KL-T2Q-T	4N70KG-T2Q-T	TO-262	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

4N70KL-	TF3-T (1)Packing Type (2)Package Type (3)Green Package	 (1) T: Tube, R: Tape Reel (2) TF3: TO-220F, TF1: TO-220F1, TF1: TO-220F2 TF3T: TO-220F3, TM3: TO-251, TMS: TO-251S TN3: TO-252, TND: TO-252D, T2Q: TO-262 (3) L: Lead Free, G: Halogen Free and Lead Free



MARKING





PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V _{DSS}	700	V	
Gate-Source Voltage		V _{GSS}	±30	V	
Avalanche Current (Note 2)		I _{AR}	4.0	А	
Drain Current	Continuous	I _D	4.0	А	
Drain Current	Continuous ID Pulsed (Note 2) IDM Single Pulsed (Note 3) EAS Repetitive (Note 2) EAR TO-220F/TO-220F1/ TO-220F2/TO-220F3	I _{DM}	17.6	Α	
Avelopebo Energy	Single Pulsed (Note 3)	E _{AS}	700 ±30 4.0 4.0 17.6 216 10.6 36 49 106 4.5 V	mJ	
Avalanche Energy	Repetitive (Note 2)	E _{AR}		mJ	
			36	W	
	TO-220F2/TO-220F3		00	vv	
Power Dissipation	TO-251/TO-251S	PD	49	W	
	TO-252/TO-252D			•••	
	TO-262		106	W	
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns	
Junction Temperature		TJ	+150	°C	
Operating Temperature		T _{OPR}	-55 ~ +150	°C	
Storage Temperature		T _{STG}	-55 ~ +150	°C	

■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature

3. L = 27mH, I_{AS} = 4 A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

4. $I_{SD} \le 4.0A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220F/TO-220F1/ TO-220F2/TO-220F3 TO-262	θ _{JA}	62.5	°C/W
	TO-251/TO-251S TO-252/TO-252D		110	°C/W
Junction to Case	TO-220F/TO-220F1 TO-220F3		3.47	°C/W
	TO-220F2	0	3.28	°C/W
	TO-251/TO-251S TO-252/TO-252D	θ _{JC}	2.55	°C/W
	TO-262		1.18	°C/W

		,					
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} = 0 V, I _D = 250 μA	700			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} = 700 V, V _{GS} = 0 V			10	μA
Gate-Source Leakage Current	Forward	- I _{GSS}	V_{GS} = 30 V, V_{DS} = 0 V			100	50
	Reverse		V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS} / \triangle T_J$	I_D = 250µA, Referenced to 25°C		0.6		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} = V _{GS} , I _D = 250 μA	2.0		4.0	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} = 10 V, I _D = 2 A			3.5	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{ISS}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1MHz		660	760	pF
Output Capacitance		C _{OSS}			48	90	pF
Reverse Transfer Capacitance		C _{RSS}			5	11	pF
SWITCHING CHARACTERISTIC	S						
Turn-On Delay Time		t _{D(ON)}	V _{DD} = 30V, I _D = 0.5A,		45		ns
Turn-On Rise Time		t _R			32		ns
Turn-Off Delay Time		t _{D(OFF)}	$R_{G} = 25\Omega$ (Note 1, 2)		80		ns
Turn-Off Fall Time		t⊧			24		ns
Total Gate Charge		Q_{G}	V _{DS} = 50V, I _D = 1.3A,		37		nC
Gate-Source Charge		Q_{GS}	V_{GS} = 50V, I_D = 1.3A, V_{GS} = 10 V (Note 1, 2)		4.8		nC
Gate-Drain Charge		Q_{GD}	$-V_{GS} = 10 V (NOLE 1, 2)$		6.0		nC
SOURCE- DRAIN DIODE RATIN	GS AND CH	HARACTERIS	TICS				
Drain-Source Diode Forward Volta	age	V_{SD}	V_{GS} = 0 V, I _S = 4.0 A			1.4	V
Maximum Continuous Drain-Sour	ontinuous Drain-Source Diode					4.0	^
Forward Current		ls				4.0	A
Maximum Pulsed Drain-Source D	iode	la.				17.6	А
Forward Current		I _{SM}				17.0	~

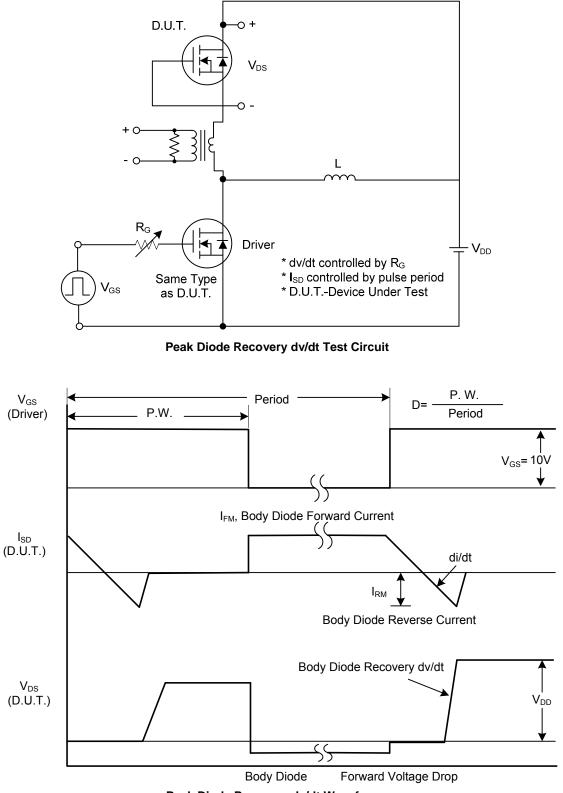
■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%

2. Essentially independent of operating temperature



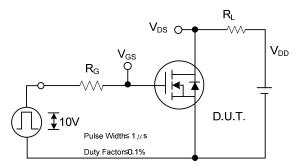
TEST CIRCUITS AND WAVEFORMS



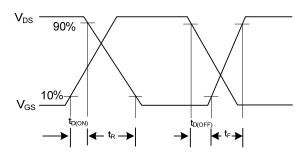
Peak Diode Recovery dv/dt Waveforms



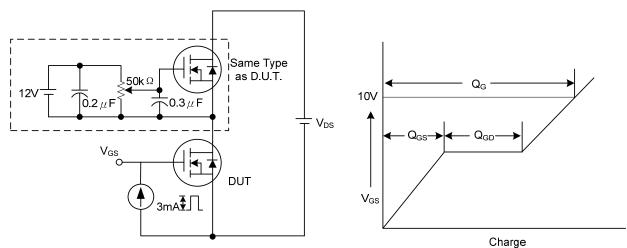
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



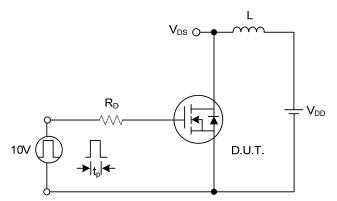
Switching Test Circuit



Switching Waveforms

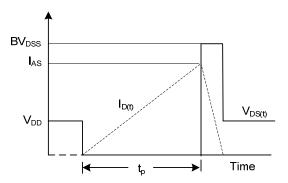


Gate Charge Test Circuit



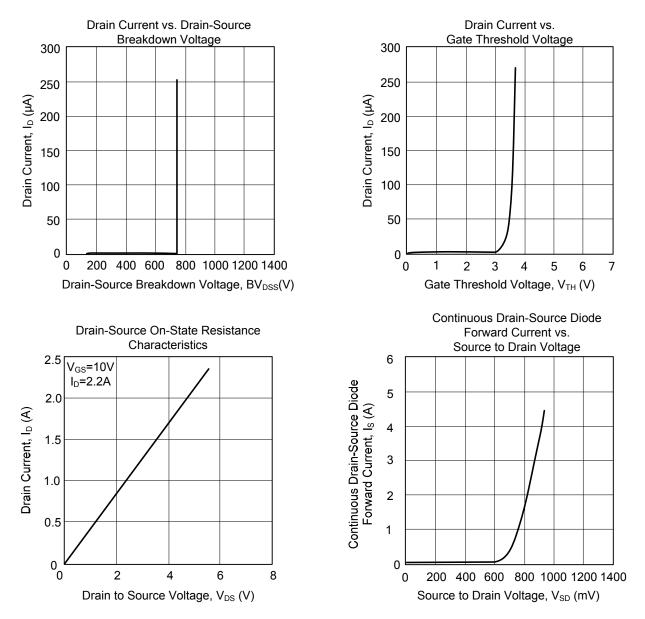
Unclamped Inductive Switching Test Circuit

Gate Charge Waveform



Unclamped Inductive Switching Waveforms

TYPICAL CHARACTERISTICS



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